September 2001 Revised December 2001

FIN1022 2 X 2 LVDS High Speed Crosspoint Switch

General Description

FAIRCHILD

SEMICONDUCTOR

This non-blocking 2x2 crosspoint switch has a fully differential input to output data path for low noise generation and low pulse width distortion. The device can be used as a high speed crosspoint switch, 2:1 multiplexer, 1:2 demultiplexer or 1:2 signal splitter. The inputs can directly interface with LVDS and LVPECL levels.

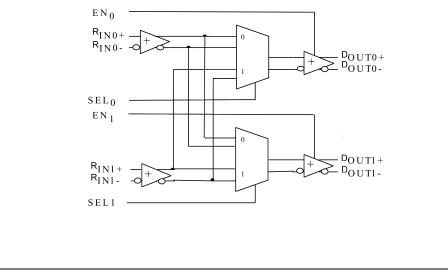
Features

- Low jitter, 800 Mbps full differential data path
- Worst case jitter of 190ps with PRBS = $2^{23} - 1$ data pattern at 800 Mbps
- Rail-to-rail common mode range is 0.5V to 3.25V
- Worst case power dissipation is less than 126 mW
- Open-circuit fail safe protection
- Fast switch time of 1.1 ns typical
- 35 ps typical pin channel to channel skew
- 3.3V power supply operation
- Non-blocking switch
- LVDS receiver inputs accept LVPECL signals directly
- 7.5 kV HBM ESD protection
- 16-lead SOIC package and TSSOP package
- Inter-operates with TIA/EIA 644-1995 specification
- See the Fairchild Interface Solutions web page for cross reference information: www.fairchildsemi.com/products/interface/lvds.html

Ordering Code:

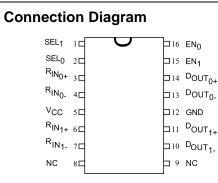
Order Number	Package Number	Package Description			
FIN1022M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
FIN1022MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide			
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.					

Logic Symbol



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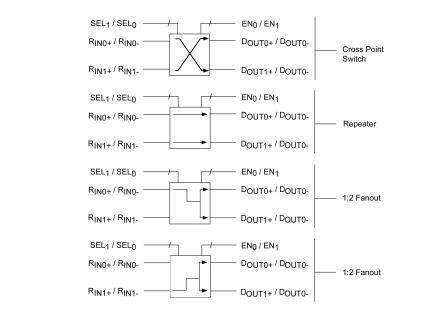
Pin Descriptions

Pin Name	Description
R _{IN0+} , R _{IN1+}	LVDS non-inverting data inputs
R _{IN0-} , R _{IN1-}	LVDS inverting data inputs
D _{OUT0+} , D _{OUT1+}	LVDS non-inverting data outputs
D _{OUT0-} , D _{OUT1-}	LVDS inverting data outputs
EN ₀	LVTTL input for enabling D _{OUT0+} /D _{OUT0-}
EN ₁	LVTTL input for enabling D _{OUT1+} /D _{OUT1-}
SEL0	LVTTL input for selecting R_{IN0+}/R_{IN0-} or R_{IN1+}/R_{IN1-} for output D_{OUT0+}/D_{OUT0-}
SEL1	LVTTL input for selecting R_{IN0+}/R_{IN0-} or R_{IN1+}/R_{IN1-} for output D_{OUT1+}/D_{OUT1-}
V _{CC}	Power Supply
GND	Ground

Function Table

	Inputs				Out	puts	Mode			
SEL ₀	SEL ₁	EN ₀	EN ₁	D _{OUT0+}	D _{OUT0-}	D _{OUT1+}	D _{OUT1-}	wode		
L/O	L/O	Н	Н	R _{IN0+}	R _{IN0-}	R _{IN0+}	R _{IN0-}	1:2 Splitter		
L/O	Н	Н	Н	R _{IN0+}	R _{IN0-}	R _{IN1+}	R _{IN1-}	Repeater		
Н	L/O	Н	Н	R _{IN1+}	R _{IN1-}	R _{IN0+}	R _{IN0-}	Switch		
Н	Н	Н	Н	R _{IN1+}	R _{IN1-}	R _{IN1+}	R _{IN1-}	1:2 Splitter		
Х	L/O	L/O	Н	Z	Z	R _{IN0+}	R _{IN0-}	D _{OUT0} Disabled		
Х	Н	L/O	Н	Z	Z	R _{IN1+}	R _{IN1-}	D _{OUT0} Disabled		
L/O	Х	Н	L/O	R _{IN0+}	R _{IN0-}	Z	Z	D _{OUT1} Disabled		
Н	Х	Н	L/O	R _{IN1+}	R _{IN1-}	Z	Z	D _{OUT1} Disabled		
Х	Х	L/O	L/O	Z	Z	Z	Z	D _{OUT0} and D _{OUT1} Disabled		
OPEN	L / O = LOV	V or OPEN	H = HI	GH Logic Lev	vel L=	LOW Logic	Level	X = Don't Care Z = High Imped		

Function Diagrams



Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.3V to +4.6V
DC Input Voltage (V _{IN})	-0.3V to +4.6V
DC Output Voltage (V _{OUT})	-0.3V to +4.6V
Driver Short Circuit Current (I _{OSD})	Continuous
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Max Junction Temperature (T _J)	150°C
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions

Supply Voltage (V _{CC})	3.0V to 3.6V
Input Voltage (V _{IN})	0 to V _{CC}
Operating Temperature (T _A)	$-40^{\circ}C$ to $+85^{\circ}C$
Electrostatic Discharge	
(HBM 1.5 kΩ, 100 pF)	>7500V
Electrostatic Discharge	
(MM 0Ω, 100 pF)	>300V
Note 1: The "Absolute Maximum Patings": are the	se values beyond which

Note 1: The "Absolute Maximum Ratings": are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature and output/input loading variables. Fairchild does not recommend operation of circuits outside databook specification.

DC Electrical Characteristics

Over supply voltage and operating temperature ranges, unless otherwise specified (Note 2)

Symbol	Parameter	Test Conditions	Min	Typ (Note 3)	Max	Units	
LVDS Diffe	erential Driver Characteristics			1 1			
V _{OD}	Output Differential Voltage	$R_L = 75 \Omega$, See Figure 3	270	365	475		
		$R_L = 75 \Omega$, See Figure 3 $T_A = 25^{\circ}C$ and $V_{CC} = 3.3V$	285	365	440	mV	
ΔV_{OD}	V _{OD} Magnitude Change from Differential LOW-to-HIGH	$R_L = 75 \ \Omega$, See Figure 3			35	mV	
V _{OS}	Offset Voltage	See Figure 3	1.0	1.2	1.45	V	
ΔV_{OS}	Offset Magnitude Change from Differential LOW-to-HIGH	See Figure 3			35	mV	
I _{OZD}	Disabled Output Leakage Current	V _{OUT} = 3.6V or GND, Driver Disabled			±10	μA	
I _{OFF}	Power-Off Current	$V_{CC} = 0V$, V_{IN} or $V_{OUT} = 3.6V$ or $0V$			±20	μA	
I _{OS} Shor	Short Circuit Output Current	V _{OUT} = 0V, Driver Enabled			-10	mA	
		V _{OUTx+} = 0V, V _{OUTx-} = 0V, Driver Enabled			-10		
LVDS Diffe	erential Receiver Characteristics						
V _{TH}	Differential Input Threshold HIGH	V _{IC} = 0.05V or 1.2V or 3.25V			100	mV	
V _{TL}	Differential Input Threshold LOW	$V_{CC} = 3.3V$	-100			mv	
VIC	Input Common Mode Voltage		0.05		3.25	V	
I _{IND}	Input Current (Differential Inputs)	V _{IN} = GND			±20	μA	
	1	V _{IN} = V _{CC}			±20	- μΑ	
LVTTL Cor	ntrol Characteristics						
VIH	Input High Voltage		2			V	
V _{IL}	Input Low Voltage				0.8	V	
I _{IN}	Input Current	V _{IN} = 3.6V or GND			±20	μΑ	
Device Cha	aracteristics						
V _{IK}	Input Clamp Voltage	$I_{IK} = -18 \text{ mA}$	-1.5			V	
I _{PU/PD}	Output Power-Up/Power-Down High Z Leakage Current	$V_{CC} = 0V$ to 1.5V			±10	μΑ	
C _{IN}	Input Capacitance			4.5		pF	
C _{OUT}	Output Capacitance			4.5		pF	
Icc	Power Supply Current	No Load, All Drivers Enabled			35	mA	
		$R_L = 75 \Omega$, All Drivers Enabled			35	mA	
		$R_L = 75 \Omega$, All Drivers Enabled			35	mA	

Note 2: This part will only function with datasheet specification when a resistive load is applied to the driver outputs.

Note 3: All typical values are at T_A = 25°C and with V_{CC} = 3.3V.

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AC Electrical Characteristics Over supply voltage and operating temperature ranges, unless otherwise specified

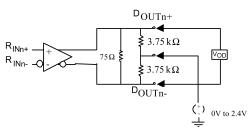
Symbol	Parameter	Test Conditions	Min	Typ (Note 4)	Max	Units		
t _{PLHD}	Differential Output Propagation Delay		0.7		1.6			
	LOW-to-HIGH	$R_L = 75 \ \Omega, \ C_L = 5 \ pF$,	1.0	1.2	1.3	ns		
t _{PHLD}	Differential Output Propagation Delay	$V_{CC} = 3.3 V$, $T_A = 25^{\circ}C$	0.7		1.6	ns		
	HIGH-to-LOW	See Figure 4 and Figure 5	1.0	1.2	1.3	ns		
t _{TLHD}	Differential Output Rise Time (20% to 80%)		290		580	ps		
t _{THLD}	Differential Output Fall Time (80% to 20%)		290		580	ps		
t _{PLH}	Selection Propagation Delay		0.6		1.5			
	LOW-to-HIGH (SEL _n to OUT _n)	$R_L = 75 \Omega$, $C_L = 5 pF$,	0.9	1.1	1.2	ns		
t _{PHL}	Selection Propagation Delay	$V_{CC} = 3.3V, T_A = 25^{\circ}C$	0.6		1.5	ns		
	HIGH-to-LOW (SEL _n to OUT _n)	See Figure 6 and Figure 7	0.9	1.1 1.2	ns			
^t ZHD	Differential Output Enable Time				3.5			
	from Z-to-HIGH				3.5	ns		
t _{ZLD}	Differential Output Enable Time				3.5			
	from Z-to-LOW	$R_L = 75\Omega$, $C_L = 5 \text{ pF}$			3.5	ns		
t _{HZD}	Differential Output Disable Time	See Figure 8 and Figure 9			3.5			
	from HIGH-to-Z				3.5	ns		
t _{LZD}	Differential Output Disable Time				3.5			
	from LOW-to-Z				3.5	ns		
t _{SET}	Input (IN _{n+} /IN _{n-}) Setup Time to SEL _n	See Figure 10	0.5	0.3		ns		
t _{HOLD}	Input (IN _{n+} /IN _{n-}) Hold Time to SEL _n	See Figure 10	0.5	0.3		ns		
t _{JIT}	Output Peak-to-Peak Jitter	2 ²³ –1 PRBS Sequence at 800 Mbps			190	ps		
		50% Duty Cycle at 800 Mbps		20	35	ps		
f _{тос}	Maximum Toggle Frequency	$R_L = 75 \Omega$, $C_L = 5 pF$, See Figure 4	800	900		Mbps		
t _{SKEW}	Within Device Channel-to-Channel Skew			35	80	ps		
	Pulse Skew t _{PLHD} -t _{PHLD}			0	225	ps		
	Part-to-Part Skew (Note 5)			100	500	ps		

Note 4: All typical values are at $T_A = 25^{\circ}C$ and with $V_{CC} = 3.3V$.

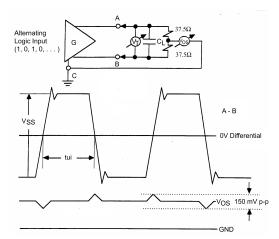
Note 5: Part-to-part skew is the maximum delay time difference on like edges (LOW-to-HIGH or HIGH-to-LOW) for the same V_{CC} and temperature conditions.

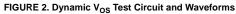
Required Specifications

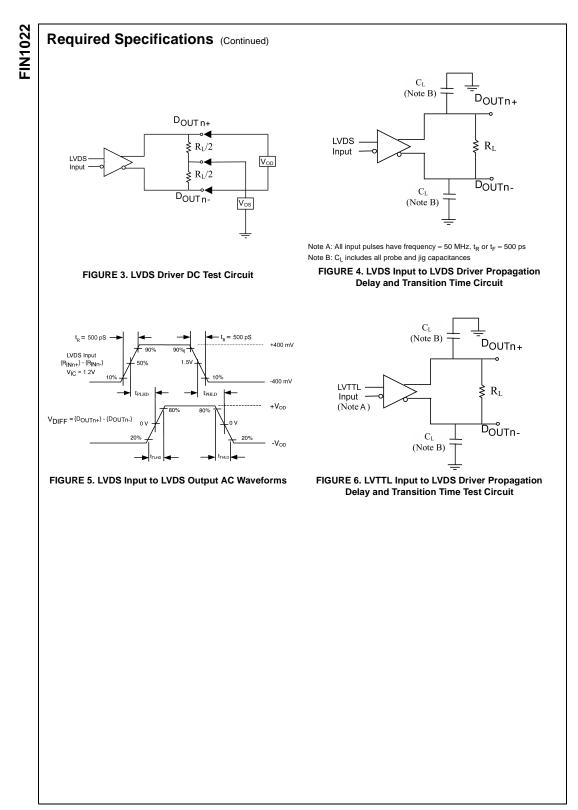
- 1. When the true and complement LVDS outputs (having a 75 Ω connected between outputs) are connected to 3.75 k Ω resistors and the common point of those 3.75 k Ω resistors are connected to a voltage source that sweeps from 0 to 2.4V, the DC V_{OD} and Δ V_{OD} are still maintained (see Figure 1).
- 2. When the true and complement LVDS outputs (having a 5 pF capacitor attached between outputs) are connected with 37.5Ω resistors each to common point, then the common point does not vary by more than 150 mV under all process, temperature and voltage conditions when the outputs switch either from LOW-to-HIGH or from HIGH-to-LOW (see Figure 2).
- 3. Pull-down resistors are required on Enable (EN₀ and EN₁) and select (SEL₀ and SEL₁) inputs.
- 4. Fail safe protection on the outputs that draw less than 20 μ A of current (worst case) on the LVDS inputs. In this condition, if the input is in fail safe selected to OUT₀₊/OUT₀₋ (say) and the outputs are Enabled then OUT₀₊ = HIGH and OUT₀₋ = LOW. This prevents noise from being amplified when the connection is broken.
- 5. In the disabled state the outputs can go beyond V_{CC} but there should be no appreciable leakage (see I_{OZD} and I_{OFF} specifications)

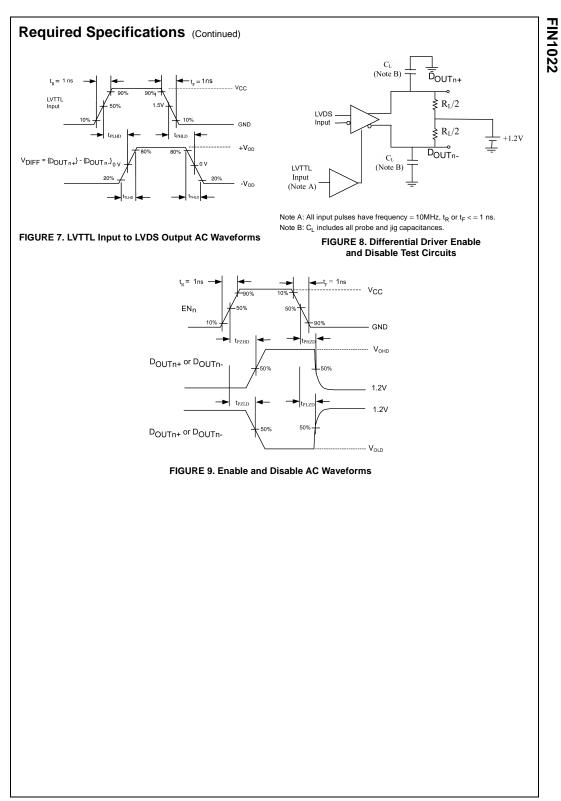


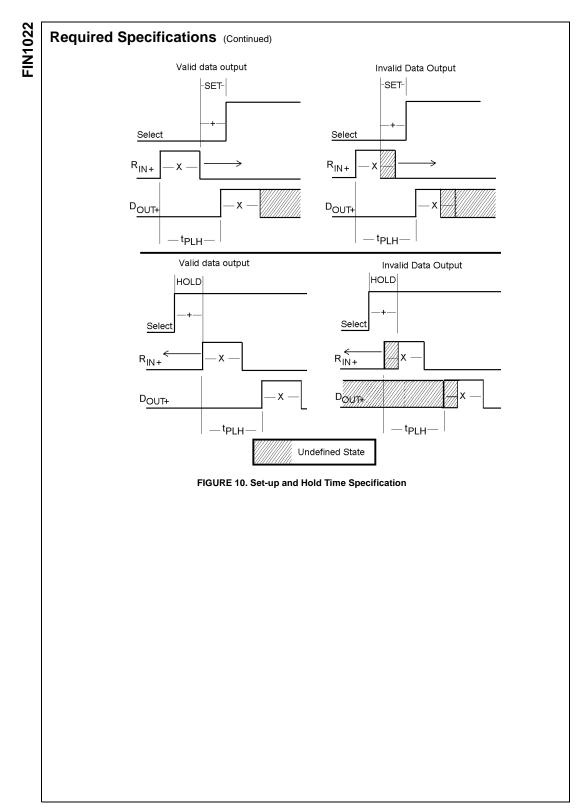


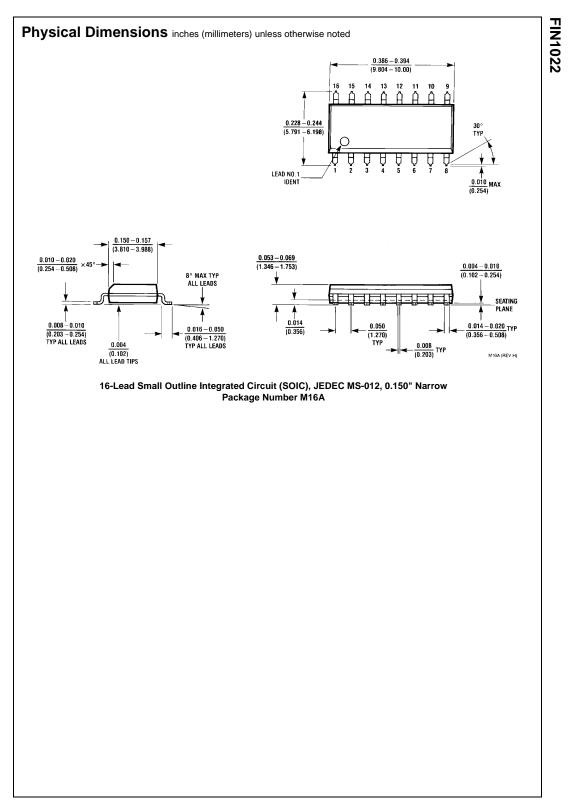




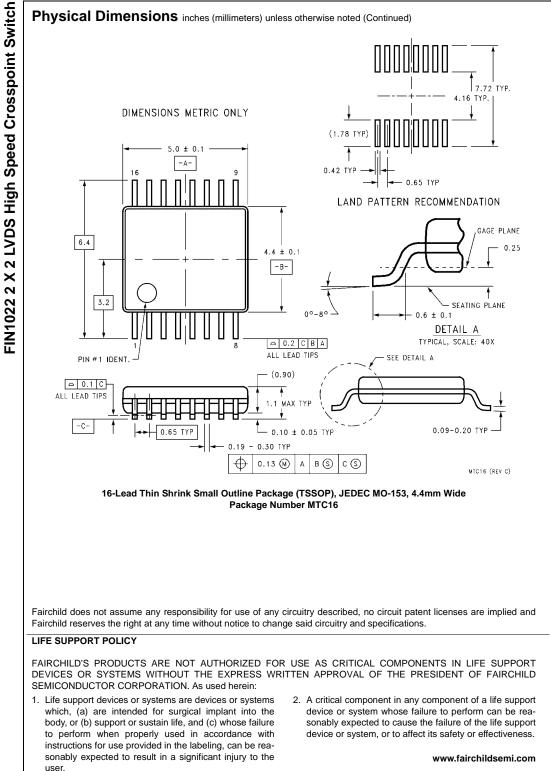








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